imall

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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



CNZ1120 (ON1120)

Photo Interrupter

For contactless SW and object detection

Overview

CNZ1120 is a photocoupler in which a high efficiency GaAs infrared light emitting diode is used as the light emitting element, and a high sensitivity phototransistor is used as the light detecting element. The two elements are arranged so as to face each other, and objects passing between them are detected.

Features

- Wide gap between emitting and detecting elements, suitable for thick plate detection Gap: 10 mm
- Fast response: t_r , $t_f = 6 \mu s$ (typ.)
- The external case is molded using visible light cutoff resin. The case has no openings, so the photosensor is not easily susceptible to output attenuation resulting from dust or particles

F	Symbol	Rating	Unit						
Input (Light emitting diode)	Power dissipation *1	PD	75	mW					
	Forward current	I _F	50	mA					
	Reverse voltage	V _R	3	V V					
Output (Photo transistor)	Collector-emitter voltage (Base open)	V _{CEO}	20	V					
	Emitter-collector voltage (Base open)	V _{ECO}	5 (N)	Y					
	Collector current	IC	20	mA					
	Collector power dissipation *2	P _C	100	mW					
Operating ambient temp	T _{opr}	-5 to +60	°C						
Storage temperature	T _{stg}	-15 to +65	°C						

Absolute Maximum Ratings $T_a = 25^{\circ}C$

Note) *1: Input power derating ratio is 1.88 mW/°C at $T_a \ge 25^{\circ}C$.

*2: Output power derating ratio is 2.50 mW/°C at $T_a \ge 25^{\circ}C$.

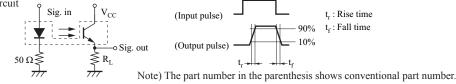
Electrical-Optical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter		Symbol	Conditions	Min	Тур	Max	Unit
Input	Reverse current	I _R	$V_R = 3 V$			10	μΑ
characteristics	Forward voltage	V _F	$I_F = 50 \text{ mA}$		1.2	1.5	V
Output characteristics	Collector-emitter cutoff current (Base open)	I _{CEO}	$V_{CE} = 10 \text{ V}, I_F = 0 \text{ mA}, I_D = 0 \text{ mA}$ (No background light)			200	nA
	Collector current	I _C	$V_{CC} = 10 \text{ V}, I_F = 20 \text{ mA}, R_L = 100 \Omega$	1.0			mA
Transfer	Collector-emitter saturation voltage	V _{CE(sat)}	$I_F = 50 \text{ mA}, I_C = 0.1 \text{ mA}$			0.4	V
characteristics	Rise time *	t _r	$V_{CC} = 10 \text{ V}, I_C = 1 \text{ mA},$		6	200	μs
	Fall time *	t _f	$R_L = 100 \Omega$		6	200	μs

Note) 1. Input and output are practiced by electricity.

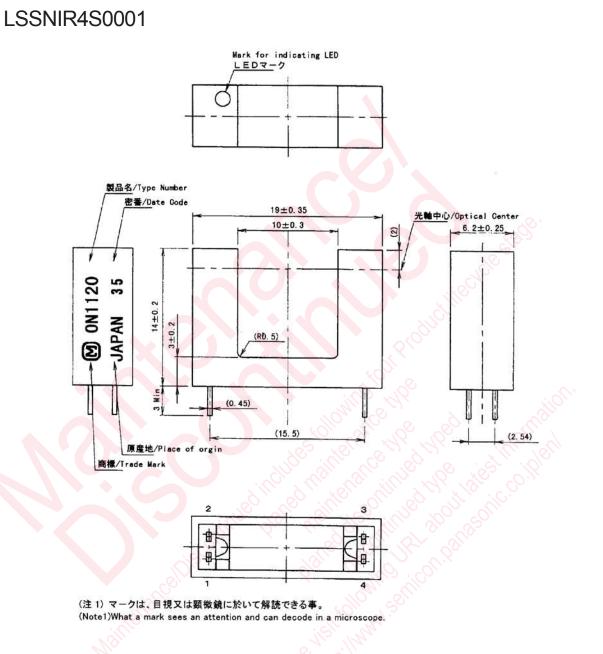
2. This device is designed by disregarding radiation.

3. *: Switching time measurement circuit



CNZ1120

Package (Unit: mm)



- Pin name
 - 1: Anode
 - 2: Cathode
 - 3: Collector
 - 4: Emitter

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